

# IPB80N04S304ATMA1

## IPB80N04S304ATMA1 Information

| www.hersener.com   | <br>IPB80N04S304ATMA1<br>Infineon Technologies<br>Discrete Semiconductor Products<br>Transistors - FETs, MOSFETs - Single<br>MOSFET N-CH 40V 80A TO263-3<br>TO-263-3, D2Pak (2 Leads + Tab), TO-263AB<br>For the pricing/inventory/lead time, please contact |                 |
|--------------------|--|-----------------|
| For Reference Only | us<br>Website: https://www.heisener.com<br>E-mail: salesdept@heisener.com  | Request a Quote |

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# IPB80N04S304ATMA1 Specifications

| Manufacturer Part Number               | IPB80N04S304ATMA1                         |                       |  |
|--|---|-----------------------|--|
| Manufacturer                           | Infineon Technologies                     | Infineon Technologies |  |
| Category                               | Discrete Semiconductor Products           |                       |  |
|  | Transistors - FETs, MOSFETs - Single      |                       |  |
| Package                                | TO-263-3, D2Pak (2 Leads + Tab), TO-263AB |                       |  |
| Series                                 | OptiMOS?                                  |                       |  |
| FET Type                               | N-Channel                                 |                       |  |
| Technology                             | MOSFET (Metal Oxide)                      |                       |  |
| Drain to Source Voltage (Vdss)         | 40V                                       |                       |  |
| Current - Continuous Drain (Id) @ 25°C | 80A (Tc)                                  |                       |  |
| Drive Voltage (Max Rds On, Min Rds On) | 10V                                       |                       |  |
| Vgs(th) (Max) @ Id                     | 4V @ 90µA                                 |                       |  |
| Gate Charge (Qg) (Max) @ Vgs           | 80nC @ 10V                                |                       |  |
| Input Capacitance (Ciss) (Max) @ Vds   | 5200pF @ 25V                              |                       |  |
| Vgs (Max)                              | ±20V                                      |                       |  |
| FET Feature                            | -   |                       |  |
| Power Dissipation (Max)                | 136W (Tc)                                 |                       |  |
| Rds On (Max) @ Id, Vgs                 | 3.8 mOhm @ 80A, 10V                       |                       |  |
| Operating Temperature                  | -55°C ~ 175°C (TJ)                        |                       |  |
| Mounting Type                          | Surface Mount                             |                       |  |
| Supplier Device Package                | PG-TO263-3-2                              |                       |  |
| Package / Case                         | TO-263-3, D2Pak (2 Leads + Tab), TO-263AB |                       |  |
|  |   | Report errors?        |  |

### IPB80N04S304ATMA1 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### IPB80N04S304ATMA1 Payment Methods



If you have any question about IPB80N04S304ATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com